

Ultrafast Soft Recovery Diode

16A 600V trr ~ 35 ns

Features

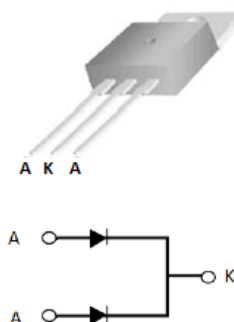
Ultrafast Recovery
 175°C operating junction temperature
 Designed and qualified for industrial level

Benefits

Reduced RFI and EMI
 Higher frequency operation
 Reduced snubbing
 Reduced part count

Description/Applications

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning system. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where switching losses are not significant portion of the total losses.



Absolute Maximum Ratings T_c = 25 °C unless otherwise noted

| Symbol | Parameter | Test Condition | Values | Units |
|-----------------------------------|---|------------------------|-------------|-------|
| V _R | Cathode – Anode voltage | -- | 600 | V |
| I _{F(AV)} | Continuous forward current | T _c = 25 °C | 16 | A |
| I _{FSM} | Single pulse forward current | T _c = 25 °C | 160 | A |
| I _{FRM} | Maximum repetitive forward current | Square wave 20 kHz | 32 | A |
| T _J , T _{STG} | Operating and Storage Temperature Range | -- | -55 to +175 | °C |

Thermal characteristics

| Symbol | Parameter | Values | Units |
|------------------|--------------------------------------|--------|-------|
| R _{θJC} | Thermal Resistance, Junction-to-Case | 0.6 | °C/W |

Electrical Characteristics T_J = 25 °C unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Units |
|----------------------------------|-------------------------------------|---|-----|------|------|-------|
| V _{BR} , V _R | Breakdown Voltage, Blocking Voltage | I _R = 100 uA | 600 | -- | -- | V |
| V _F | Forward voltage | I _F = 16 A, T _J = 25 °C | -- | 1.45 | 1.75 | V |
| | | I _F = 16 A, T _J = 125 °C | -- | 1.35 | 1.65 | V |
| I _R | Reverse Leakage Current | V _R = V _{R rated} | -- | -- | 1 | uA |
| | | V _R = V _{R rated} , T _J = 150 °C | -- | -- | 100 | uA |
| trr | Reverse recovery time | I _F = 0.5A, I _R = 1A, I _{RR} = 0.25A | -- | -- | 35 | ns |
| | | I _F = 1A, V _R = 30V, di/dt = -200A/us | -- | -- | 35 | ns |

Package Information

